



ZXGD3003E6

40V 5A GATE DRIVER IN SOT26

Description

The ZXGD3003E6 is a high-speed, non-inverting single gate driver designed for switching MOSFETs or IGBTS. It can transfer up to 5A peak source/source current into the gate for effective charging and discharging of the capacitive gate load.

This gate driver ensures rapid switching of the MOSFET to minimize power losses and distortion in high current switching applications. It can typically drive 1.5A into the low gate impedance with just 10mA input from a controller. The turn-on and turn-off switching behaviour of the MOSFET can be individually tailored to suit an application. By defining the switching characteristics appropriately, EMI and cross conduction can be reduced.

Applications

Gate Driving Power MOSFET and IGBTs in:

- AC-DC Power Supplies (SMPS)
- DC-DC Converters
- DC-AC Inverters (i.e. Solar)
- 1, 2 and 3-Phase Motor Control Circuits
- Amplifier Output Stages

Features

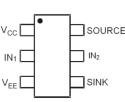
- High-Gain Buffer with Typically 1.5A Output from 10mA Input
- 5 Amps Peak Output Current
- 40V Supply for +20V to -18V Gate Driving to Prevent dV/dt Induced False Triggering and Minimize On-Losses
 - Emitter-Follower that is Rugged to Latch-Up/Shoot-Though
- Fast Switching Emitter-Follower Configuration:
 - 2ns Propagation Delay Time
 - 9ns Rise/Fall Time, 1000pF Load
- Optimized Pin-Out to Simplify PCB Layout and Reduce
 Parasitic Trace Inductances
- Near-Zero Quiescent Supply Current
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Qsuffix) part. A listing can be found at <u>https://www.diodes.com/products/automotive/automotiveproducts/</u>.
- This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability. <u>https://www.diodes.com/quality/product-definitions/</u>
- An Automotive-Compliant Part is Available Under Separate Datasheet (<u>ZXGD3003E6Q</u>)

Mechanical Data

- Case: SOT26
- Case Material: Molded Plastic. "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (€3)
- Weight: 0.018 grams (Approximate)

IN2	Top View

SOT26



Top View

Pin-Out

Pin Name	Pin Function
Vcc	Supply Voltage High
IN1 & IN2	Driver Input *
VEE	Supply Voltage Low
SOURCE	Source Current Output **
SINK	Sink Current Output **
* Tunia allus as	anne a tINIA 9 INIO ta math an

* Typically connect IN1 & IN2 together ** Typically connect SOURCE & SINK together

Ordering Information (Note 4)

Product	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
ZXGD3003E6TA	AEC-Q101	3003	7	8	3,000

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



Marking Information



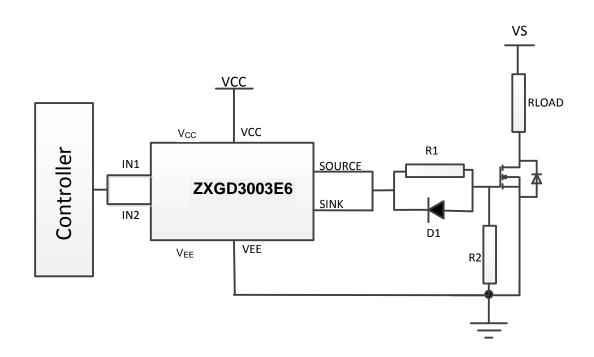


3003 = Product Type Marking Code YM = Date Code Marking Y or \overline{Y} = Year (ex: H = 2020) M or \overline{M} = Month (ex: 9 = September)

Date Code Key

Year	2010		2020	2021	2022	2023	2024	2025	2026	2027	2028	2029
Code	Х		Н		J	К	L	М	N	0	Р	R
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec

Typical Application Circuit



R1, D1 combination can be used for variable turn on and turn off times.



Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Supply Voltage, with Respect to VEE	Vcc	40	V
Input Voltage, with Respect to V _{EE}	V _{IN}	40	V
Output Difference Voltage (Source – Sink)	$\Delta V_{(source-sink)}$	±7	V
Peak Pulsed Output Current (Source – Sink)	Іом	±5	А
Peak Pulsed Input Current	lin1, lin2	±1	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Notes 5 & 6)		1.1	W
Linear Derating Factor	PD	8.8	mW/°C
Thermal Resistance, Junction to Ambient (Notes 5 & 6)	R _{0JA}	113	°C/W
Thermal Resistance, Junction to Lead (Note 7)	Rejl	105	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С
Electrostatic Discharge – Charged Device Model	ESD CDM	1,000	V	IV

Notes: 5. For a device mounted on 25mm x 25mm 1oz copper that is on a single-sided 1.6mm FR-4 PCB; device is measured under still air conditions whilst operating in a steady-state. The heatsink is split in half with the pin 1 (V_{CC}) and pin 3 (V_{EE}) connected separately to each half.

6. For device with two active die running at equal power.

7. Thermal resistance from junction to solder-point at the end of each lead on pin 1 (V_{CC}) and pin 3 (V_{EE}).

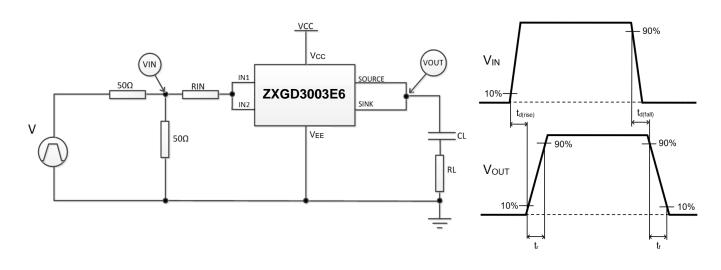
8. Refer to JEDEC specification JESD22-A114, JESD22-A115 and JESD22-C101.



Electrical Characteristics	(@T _A = +25	°C, unless	otherwise spe	cified.)		
Characteristic	Symbol	Min	Тур	Max	Unit	

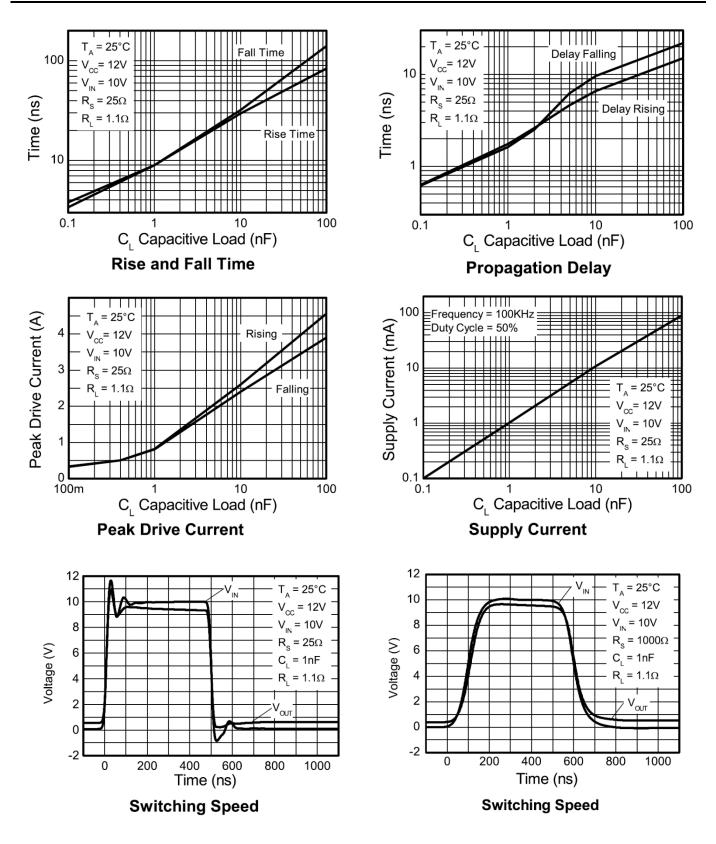
Characteristic	Symbol	Min	Тур	Мах	Unit	Test Condition
Output Voltage, High	Vout(hi)	—	V _{IN1} - 0.4	—	v	I _{source} = 1µA
Output Voltage, Low	V _{OUT(low)}	—	V _{IN1} + 0.4	—	v	$I_{sink} = 1\mu A$
Source Output Leakage Current	I _{L(source)}	—	—	1	μΑ	
Sink Output Leakage Current	I _{L(sink)}	_	—	1	μΑ	Vcc = 40V, VIN1 = VIN2 = Vcc
Quiescent Supply Current	lq	_	_	20	nA	$V_{CC} = 32V,$ $V_{IN1} = V_{IN2} = 0V$
Peak Pulsed Source Output Current	I(source)M	1	1.6	—	А	$I_{IN1} + I_{IN2} = 10 \text{mA}$
Peak Pulsed Sink Output Current	l(sink)M	1	1.4	—	А	I _{IN1} + I _{IN2} = -10mA
Peak Pulsed Source Output Current	I(source)M	_	5	—	А	I _{IN1} + I _{IN2} = 500mA
Peak Pulsed Sink Output Current	I(sink)M	—	5	—	А	I _{IN1} + I _{IN2} = -500mA
Gate Driver Switching Times	t _{d(rise)} tr t _{d(fall)} t _f	_	1.8 8.9 1.7 8.9	_	ns	$\begin{split} &V_{CC} = 12V, V_{EE} = 0V, \\ &V_{IN} = 0 \text{ to } 10V, \\ &C_L = 1nF, R_L = 1\Omega, \\ &R_{IN} = 25\Omega \end{split}$
Gate Driver Switching Times	td(rise) tr td(fall) tf	_	4 77 4 85	_	ns	$\begin{split} &V_{CC} = 12V, V_{EE} = 0V, \\ &V_{IN} = 0 \text{ to } 10V, \\ &C_L = 1nF, R_L = 1\Omega, \\ &R_{IN} = 1k\Omega \end{split}$

Switching Test Circuit and Timing Diagram



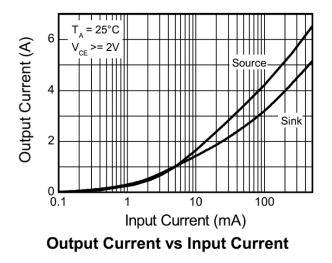


Typical Gate Driver Characteristics (@TA = +25°C, unless otherwise specified.)





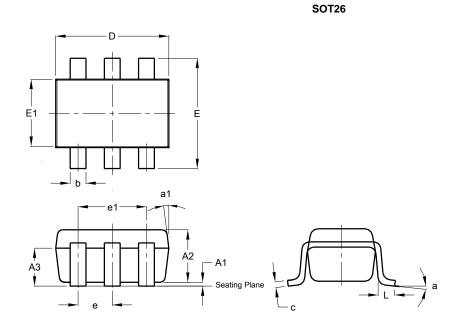
Typical Gate Driver Characteristics (continued)





Package Outline Dimensions

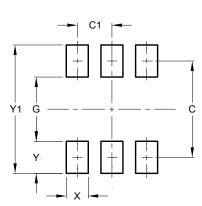
Please see http://www.diodes.com/package-outlines.html for the latest version.



	SC	DT26					
Dim	Dim Min Max T						
A1	0.013	0.10	0.05				
A2	1.00	1.30	1.10				
A3	0.70	0.80	0.75				
b	0.35	0.50	0.38				
C	0.10	0.20	0.15				
D	2.90	3.10	3.00				
е	-	-	0.95				
e1	-	-	1.90				
Е	2.70	3.00	2.80				
E1	1.50	1.70	1.60				
L	0.35	0.55	0.40				
а	-	-	8°				
a1	-	-	7°				
All	Dimen	sions	in mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	2.40
C1	0.95
G	1.60
Х	0.55
Y	0.80
Y1	3.20

SOT26



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